

# NPN SILICON PLANAR MEDIUM POWER TRANSISTOR

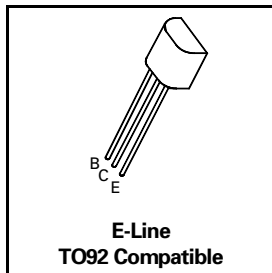
## FXT450

ISSUE 1 – SEPT 93

### FEATURES

- \* 45 Volt  $V_{CE0}$
- \* 1 Amp continuous current
- \*  $P_{tot}=1$  Watt

REFER TO ZTX450 FOR GRAPHS



### ABSOLUTE MAXIMUM RATINGS.

| PARAMETER                                  | SYMBOL         | VALUE       | UNIT        |
|--|----------------|-------------|-------------|
| Collector-Base Voltage                     | $V_{CBO}$      | 60          | V           |
| Collector-Emitter Voltage                  | $V_{CEO}$      | 45          | V           |
| Emitter-Base Voltage                       | $V_{EBO}$      | 5           | V           |
| Peak Pulse Current                         | $I_{CM}$       | 2           | A           |
| Continuous Collector Current               | $I_C$          | 1           | A           |
| Power Dissipation at $T_{amb}=25^{\circ}C$ | $P_{tot}$      | 1           | W           |
| Operating and Storage Temperature Range    | $T_j; T_{stg}$ | -55 to +200 | $^{\circ}C$ |

### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ ).

| PARAMETER                             | SYMBOL         | MIN.      | TYP. | MAX. | UNIT    | CONDITIONS.   |
|---------------------------------------|----------------|-----------|------|------|---------|---|
| Collector-Base Breakdown Voltage      | $V_{(BR)CBO}$  | 60        |      |      | V       | $I_C=100\mu A, I_E=0$                               |
| Collector-Emitter Sustaining Voltage  | $V_{CEO(SUS)}$ | 45        |      |      | V       | $I_C=10mA, I_B=0^*$                                 |
| Emitter-Base Breakdown Voltage        | $V_{(BR)EBO}$  | 5         |      |      | V       | $I_E=100\mu A, I_C=0$                               |
| Collector Cut-Off Current             | $I_{CBO}$      |           |      | 0.1  | $\mu A$ | $V_{CB}=45V, I_E=0$                                 |
| Emitter Cut-Off Current               | $I_{EBO}$      |           |      | 0.1  | $\mu A$ | $V_{EB}=4V, I_C=0$                                  |
| Collector-Emitter Saturation Voltage  | $V_{CE(sat)}$  |           |      | 0.25 | V       | $I_C=150mA, I_B=15mA^*$                             |
| Base-Emitter Saturation Voltage       | $V_{BE(sat)}$  |           |      | 1.1  | V       | $I_C=150mA, I_B=15mA^*$                             |
| Static Forward Current Transfer Ratio | $h_{FE}$       | 100<br>15 |      | 300  |         | $I_C=150mA, V_{CE}=10V^*$<br>$I_C=1A, V_{CE}=10V^*$ |
| Transition Frequency                  | $f_T$          | 150       |      |      |         | $I_C=50mA, V_{CE}=10V$<br>$f=100MHz$                |
| Output Capacitance                    | $C_{obo}$      |           |      | 15   | pF      | $V_{CB}=10V, f=1MHz$                                |